June 1989

DM54L00 Quad 2-Input NAND Gates

General Description

This device contains four independent gates each of which performs the logic NAND function.

Connection Diagram

Dual-In-Line Package Vcc B4 A4 Y4 B3 A3 Y3 14 13 12 11 10 9 B I 2 3 4 5 6 7 A1 B1 Y1 A2 B2 Y2 GND

Order Number DM54L00J or DM54L00W See NS Package Number J14A or W14B

Function Table

Y = AB				
Inputs		Output		
Α	В	Y		
L	L	Н		
L	Н	Н		
Н	L	Н		
Н	Н	L		

$$\begin{split} \mathsf{H} &= \mathsf{High} \; \mathsf{Logic} \; \mathsf{Level} \\ \mathsf{L} &= \mathsf{Low} \; \mathsf{Logic} \; \mathsf{Level} \end{split}$$

Absolute Maximum Ratings (Note)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage 8V
Input Voltage 5.5V
Operating Free Air Temperature Range
DM57L -55°C to +125°C

Storage Temperature Range $-65^{\circ}\text{C to} + 150^{\circ}\text{C}$

Note: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Recommended Operating Conditions

Symbol	Parameter		Units		
		Min	Nom	Max	Cilits
V _{CC}	Supply Voltage	4.5	5	5.5	V
V _{IH}	High Level Input Voltage	2			V
V _{IL}	Low Level Input Voltage			0.7	V
I _{OH}	High Level Output Current			-0.2	mA
l _{OL}	Low Level Output Current			2	mA
	Free Air Operating Temperature	-55		125	°C

Electrical Characteristics over recommended operating free air temperature (unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ (Note 1)	Max	Units
V _{OH}	High Level Ouput Voltage	$V_{CC} = Min, I_{OH} = Max$ $V_{IL} = Max$	2.4	3.3		V
V_{OL}	Low Level Output Voltage	$V_{CC} = Min, I_{OL} = Max$ $V_{IH} = Min$		0.15	0.3	V
I _I	Input Current @ Max Input Voltage	$V_{CC} = Max, V_I = 5.5V$			0.1	mA
I _{IH}	High Level Input Current	$V_{CC} = Max, V_I = 2.4V$			10	μΑ
I _{IL}	Low Level Input Current	$V_{CC} = Max, V_I = 0.3V$			-0.18	mA
I _{OS}	Short Circuit Output Current	V _{CC} = Max (Note 2)	-3		-15	mA
I _{CCH}	Supply Current with Outputs High	V _{CC} = Max		0.44	0.8	mA
I _{CCL}	Supply Current with Outputs Low	V _{CC} = Max		1.16	2.04	mA

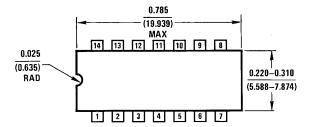
Note 1: All typicals are at $V_{CC} = 5V$, $T_A = 25^{\circ}C$.

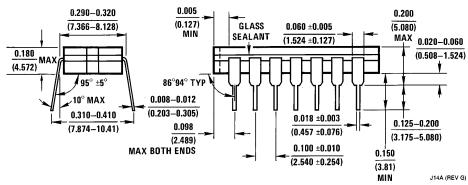
Note 2: Not more than one should be shorted at a time.

$\textbf{Switching Characteristics} \text{ at V}_{CC} = 5 \text{V and T}_{A} = 25 ^{\circ}\text{C (See Section 1 for Test Waveforms and Output Load)}$

Symbol	Parameter	Conditions	Min	Max	Units
t _{PLH}	Propagation Delay Low to High Level Output	$R_L = 4 k\Omega$ $C_L = 50 pF$		60	ns
t _{PHL}	Propagation Delay High to Low Level Output			60	ns

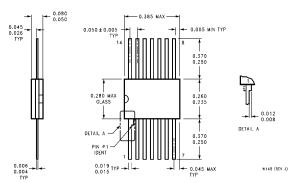






14-Lead Ceramic Dual-In-Line Package (J) Order Number DM54L00J NS Package Number J14A

Physical Dimensions inches (millimeters) (Continued)



14-Lead Ceramic Flat Package (W) Order Number DM54L00W NS Package Number W14B

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